

## The Design of T/R Module for X-Band APAA System Used in Satellite Communications

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**Abstract** — This paper is concerned with the design of the X-band T/R module that is a key unit of the active phased array antenna(APAA) system for mobile satellite communications. In this module, the TX-part is primarily composed of 3-stage power amplifier having 4-watt output power, microstrip 4-bit phase shifter(MICPS) controlling 16 phase state and thermal compensation and power detection circuit. And, the RX-part composed of LNA using hetero junction FETs, MICPS and microstrip hairpin type BPF for TX power rejection. From the standpoint of mechanic design, focus is given to the T/RX isolation that is very important to prevent LNA saturation by TX leakage power. The T/R module achieved 35.6dBm minimum  $P_{1dB}$  with 22dB linear gain in TX-part, and 26.5dB linear gain with 1.0dB noise figure in RX-part.

### I. INTRODUCTION

Since satellite communications can cover wide range, it is inherently suitable for mobile communications. And it has the advantages in propagation conditions compared to terrestrial communications since it suffers from less interference by receiving communication signal directly. In these days, therefore, as mobile direct broadcasting satellite(DBS) service has become widespread, increasing attention is paid to bilateral communication technologies via communication satellites for the purpose of commerce and military [1].

As the first model for satellite communications, Ku-band mobile APAA system was developed already by ETRI in Korea[2-5]. But it is unilateral system for satellite receptions. By the demand for bilateral communication system using satellite, ETRI launched its development, too. This system can be divided into several functional units including radiator, T/R module, satellite tracking controller(STC) and other operating units.

Several electric specifications are required for the T/R module composed of two active parts, so called active channel block(ACB), TX and RX to normally function in APAA system. And the specifications are summarized in Table 1.

TABLE I  
ELECTRICAL SPECIFICATIONS OF THE T/R MODULE

Item description	Electrical Performances	
Classification	TX	RX
RF frequency band	X-Band	
Return Loss	14dB(min)	14dB(min)
Insertion Loss	14dB(min)	14dB(min)
Linear Gain	20dB(min)	24dB(min)
Gain Flatness	±2.0dB(max)	±2.0dB(max)
Phase Control Step	22.5°	22.5°
Gain Variation by Phase Control	±2.0dB(max)	±2.0dB(max)
P1dB	35dBm(min)	-
IM3	24dBc(min)	-
T/R Isolation	-	80dBc(min)
Noise Figure	-	1.2dB(max)

### II. T/R MODULE DESIGN

The roles played by TX-ACB of the T/R module in the antenna system are beam steering for transmit signal, power amplification and function of output power monitor/report. Fig.1 shows the block diagram of TX-ACB of the T/R module. It has basically four subassemblies to accomplish the functions above mentioned; 4bit microstrip phase shifter(MICPS), temperature compensation circuit (TCC), power amplifier composed of 3-stages and power detection circuit using parallel coupled transmission lines coupler.

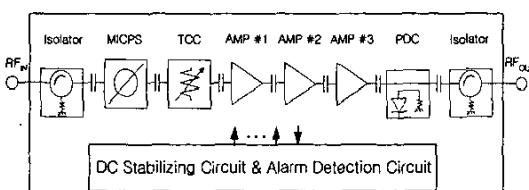


Fig.1. The block diagram of the TX-ACB

The MICPS was designed for transmit antenna beam steering. Its basic element is modified branch-line coupler that makes use of the form of quarter-wavelength coupler to realize minimum size. To satisfy system performance of beam tracking, it is composed of four hybrid branch-line couplers for 16 phase states. Each of them includes two pin diodes, and corresponds to 22.5°, 45°, 90° and 180° respectively. As shown in the schematic diagram Fig. 2, each phase bit is controlled by phase control codes, from PC1 to PC4, coming from the beam steering controller (BSC) of the APAA system.

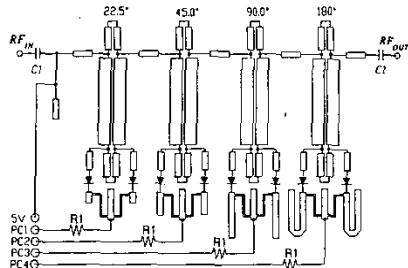


Fig.2. The Schematic diagram of the MICPS

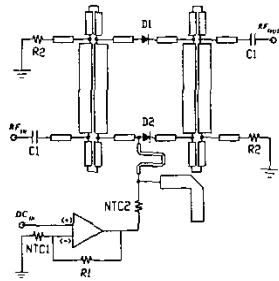


Fig.3. The Schematic diagram of the TCC

$$V_{OUT} = \left(1 + \frac{R1}{NTC1}\right) V_{IN} \quad (1)$$

$$I_D = \frac{V_{OUT}}{NTC2} \quad (2)$$

And, in order to prevent output power from being degraded by the heat generated from internal and external cause, especially power amplifier, modified variable attenuator i.e. TCC was adopted in TX-ACB. The TCC structure of Fig.3 provides thermal compensating function on the basis of temperature by NTC thermistors, and its in/output matching condition was kept by the isolation ports to which no power is coupled. And, constant output power needed for TX-ACB can be realized by variable forward resistance of pin diodes that are inversely proportional to  $I_D$  that can be expressed by equation 1 and

## 2.

For amplification of transmit signal, Power amplifier is lined-up by three GaAs FETs having output power of 0.17W, 1W and 4W respectively, and the line-up has the advantage of low-cost. In RF design, three separate designs of each of them were implemented on the same design concept by RF circuit simulator to which the S-parameters on data sheet for the optimal bias conditions were applied, and several design factors such as stability factor  $K$ , available gain circle, input/output matching conditions and so on were checked by the circuit simulator for the inter-stage matching of all stages.

The quarter-wavelength directional coupler was used for output power detection. Its coupling degree, about 35dB, was decided in the condition that the output power is not influenced by the coupled power, and for the rectification process shottky diode having good performance in X-band was chosen. The minimum available power that can be considered as normal condition is 28dBm, and the rectified DC voltage of the power is about 0.76V.

RX-ACB of the T/R module plays also several roles in the antenna system such as beam steering for satellite signal reception, low noise power amplification and the function of monitor/report for normal operation. The composition of RX-ACB to accomplish the functions is shown in Fig.4.

To satisfy the required noise performance, low noise hetero junction FET was chosen. The first LNA was designed by the concept for low noise characteristic above all. But the concept for high gain was implemented in the second and the third LNA designs. Overall design of them including input/output matching circuits was accomplished by using RF circuit simulator, and the bias condition of  $V_{ds}=2V$  and  $I_{ds}=10mA$  is needed for the optimal operation of the LNAs. The overall noise temperature of the RX-ACB can be modeled equivalently as shown in Fig.4 and calculated by equation 3 and 4.

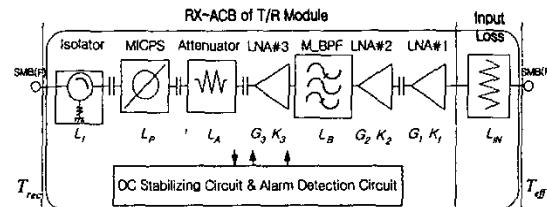


Fig.4. The Noise Model of the RX-ACB

$$T_{tot} = T_{ant} + T_{eff} \quad (3)$$

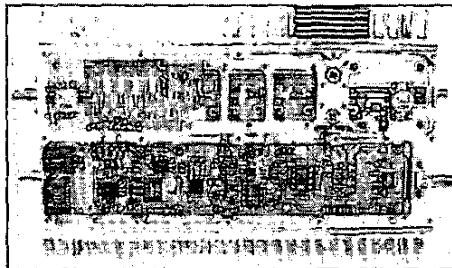
$$T_{eff} = \frac{T_{rec}}{G_{tot}} \quad (4)$$

where,

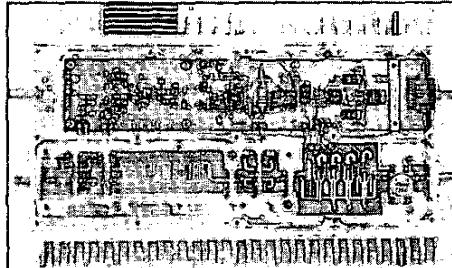
$$G_{\text{tot}} = \frac{G_1 G_2 G_3}{L_{IN} L_B L_A L_I}$$

$$T_{\text{REC}} = G_{\text{tot}} T_0 \{ [(L_{IN} - 1)] + [(K_1 - 1)L_{IN}] + \left[ \frac{(K_2 - 1)L_{IN}}{G_1} \right] + \left[ \frac{(L_B - 1)L_{IN}}{G_1 G_2} \right] + \left[ \frac{(K_3 - 1)L_{IN} L_B}{G_1 G_2} \right] + \left[ \frac{(L_A - 1)L_{IN} L_B}{G_1 G_2 G_3} \right] + \left[ \frac{(L_P - 1)L_{IN} L_B L_A}{G_1 G_2 G_3} \right] + \left[ \frac{(L_I - 1)L_{IN} L_B L_A L_P}{G_1 G_2 G_3} \right]$$

In this diagram, the position of microstrip 7-pole hairpin-line BPF(henceforth, M\_BPF) was decided by the viewpoint of noise characteristic and TX-power rejection. By the arrangement, RX-ACB has the possibility that the first two LNAs may be saturated by the leakage power of TX-ACB that is considerable in comparison with the input level of received signal. So, for the protection of the LNA saturation, the mechanic box of T/R module was designed and modified to maximize the isolation between TX and RX-ACB. Fig.5 shows the assembled T/R module. Its front side includes RF and DC board for TX, and the back side contains them for RX.



(a) Front side(TX-ACB)



(b) Back side(RX-ACB)

Fig.5. Photograph of assembled T/R module

Of the subassemblies composing RX-part,  $\pi$ -network attenuator made of lumped elements is used for manually changeable power attenuation, and MICPS was designed to be optimized in the operation band of RX by the same

design conception that was applied to the MICPS design of TX-ACB.

Finally, for the supply of constant current and voltage, the stabilized active DC bias circuits were designed. In Fig.6, alarm detection circuit for RX-ACB is shown. It is composed of two voltage comparators and two voltage dividers to establish acceptable bias range, from  $V_{LCAT}$  (Low current alarm threshold) to  $V_{HCAT}$  (High current alarm threshold). And, by the voltage setting, available drain current is about  $72\text{mA} \pm 20\%$ .

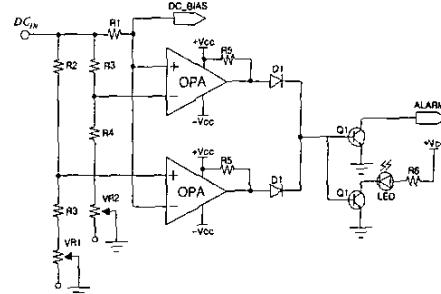


Fig.6. Alarm detection circuit for RX-ACB

### III. EXPERIMENTAL RESULTS

In order to develop the T/R module, RF boards were fabricated on a 0.508mm-thick substrate within  $\pm 0.02\text{mm}$  etching tolerance. By the consideration of mechanic box design for the isolation between T/RX channel, minimum 104dB isolation was achieved. Isolation test was accomplished with the normal operation condition that transmitted power level was 35dBm, and test results were measured at output port of RX-ACB. In Fig.7, the test results of output power and its detection voltage for TX-ACB are shown. The minimum value of  $P_{1\text{dBC}}$  was 35.6dBm at 7.9GHz, 36.8dBm at 8.15GHz and 36.0dBm at 8.4GHz respectively, with minimum gain of 22dB, and detection voltage at  $P_{1\text{dBC}}$  was about 2.1V.

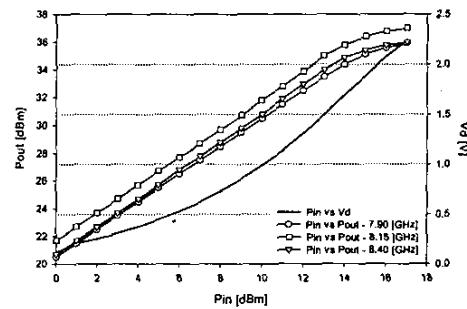


Fig.7. Output power and its detection voltage for TX-ACB

The characteristic of gain variation by temperature for TX-ACB is shown in Fig.8. Its measured value was  $\pm 0.6$ dB compared with maximum gain, and the surface temperature of T/R module ranged from 27°C to 60°C. According as the temperature increase, linear gain of TX-ACB decreased, and, at 60°C, output power was reached at equilibrium state.

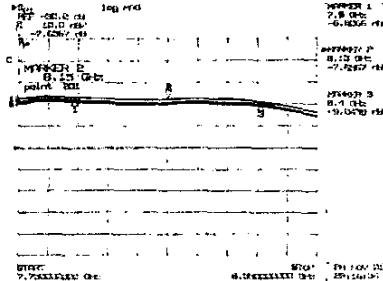


Fig.8. Gain variation by temperature for TX-ACB

\*Note : For gain test, 30dB external attenuator was used, and the total cable loss, about 1dB, was not considered.

As other performances of TX-ACB, the gain variations by phase control and temperature were about  $\pm 1.2$ dB and  $\pm 0.6$ dB within operation band. The phase response of TX-ACB by MICPS was similar to the response of RX-ACB depicted in Fig.10.

In the RX-ACB of this T/R module, it has the minimum gain of 26.5dB with 1.0dB maximum noise figure at 0-state of MICPS, and the gain variations by temperature and phase control of  $\pm 0.51$ dB and  $\pm 1.65$ dB respectively. And, the linear gain responses for each phase state of the RX-ACB are shown in Fig.9. In Fig.10, The phase response of the RX-ACB by MICPS is also shown, and it shows 4-bit operation with the resolution of 22.5° in the phase controllable range of 360°. In RX-ACB, the allowable phase error is  $\pm 11.25$ ° at all control steps.

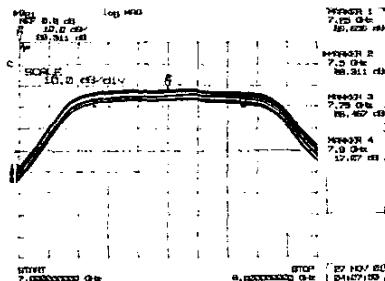


Fig.9. Gain variation by phase control for RX-ACB

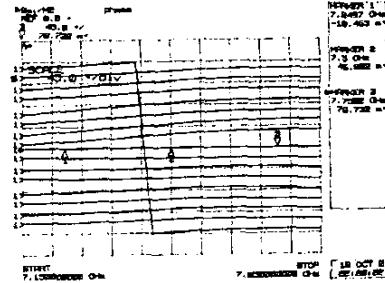


Fig.10. Phase response of RX-ACB by MICPS

And, overall tests of T/RX-ACB as stated above were accomplished under the same test conditions including equipments and environment.

#### IV. CONCLUSION

The T/R module playing several roles was designed and fabricated for the APAA system used in bilateral communications via satellite. It is a key unit of APAA system and composed of TX and RX-ACB. The TX-ACB has the performances of  $P_{1dBc}$  of 35.6dBm with 22dB gain. And, for RX-ACB, its linear gain is minimum 26.5dB with 1.0dB noise figure. All of the ACBs include a MICPS with the resolution of 22.5° for satellite tracking, and it was confirmed that the experimental results of the T/R module satisfied the performances required in the APAA system.

In the future, a lot of the T/R modules will be combined into APAA system with radiator.

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